

# **Product Overview**

## NCS210R: Current Sense Amplifier, 26V, Low-/High-Side Voltage Out. **Bidirectional Current Shunt Monitor**

For complete documentation, see the data sheet.



The NCS210R and NCV210R (AEC- Q100 qualified) are voltage output current sense amplifiers that can measure voltage across shunts at common-mode voltages from -0.3 V to 26 V, independent of supply voltage. With a fixed gain of 200 V/V, the low offset of the zero-drift architecture enables current sensing with maximum drops across the solution as 10 mV full-scale. The fixed gain of 200 V/V and for a lower than 10 mV full-scale. The fixed gain of 200 V/V and for a lower than 10 mV full-scale. The fixed gain of 200 V/V and for a lower than 10 mV full-scale in the fixed gain of 200 V/V. can operate from a single +2.2 V to +26 V power supply, drawing a maximum of 80 µA of supply current. Available in UQFN and SC70 packages

Additional gain options are available: NCS213R (50 V/V), NCS214R (100 V/V), NCS211R (500 V/V)

#### **Similar Products:**

	NCS210R	NCS211R	NCS213R	NCS214R
Gain (V/V)	200	500	50	100
Gain Error (%)	1	1	1	1
Offset Voltage (µV)	35	35	100	60

#### **Features**

• Wide common mode input range -0.3 to 26 V

 Low Offset Voltage: ±35 μV max. Low Offset Drift: 0.5 μV/°C max.

· Supply Voltage: 2.2 to 26V

### **Applications**

· Power Monitoring

· Power Adapters

LED Power Supply

· Over Current Protection

Automotive

### **Benefits**

- · High- side current sensing for high voltage systems
- · Low Ohm value current sense resistors
- · High accuracy over temperature leading to better power efficiency
- · Wide supply voltage range provides system flexibilty

#### **End Products**

- · White Goods
- Automotive
- Lighting
- · Laptop/Notebooks PC
- · Fast Chargers in Smartphones and Tablets

Part Electrical Specifications																
Product	Pricing (\$/Unit)	Compliance	Statu s	Chan nels	Gain (V/V)	Gain Error Max (%)	V <sub>s</sub> Min (V)	V <sub>s</sub> Max (V)	V <sub>CM</sub> (V)	I <sub>q</sub> Typ (mA)	Band width Typ (- 3dB)	V <sub>os</sub> Max (mV)	V <sub>os</sub> Drift Max (μV/° C)	Oper ating Temp eratur e Rang e (°C)	CMR R Typ (dB)	Pack age Type
NCS210RMUTAG	0.2467	Pb-free Halide free non AEC-Q and PPAP	Activ e	1	200	±1	2.2	26	-0.3 to 26	0.04	0.04	±0.03 5	0.5	-40 to 125	125	UQF N-10
NCS210RSQT2G	0.2467	Pb-free Halide free non AEC-Q and PPAP	Activ e	1	200	±1	2.2	26	-0.3 to 26	0.04	0.04	±0.03 5	0.5	-40 to 125	125	SC- 88-6 / SC- 70-6 / SOT- 363-6
NCV210RSQT2G	0.3067	AEC Qualified PPAP Capable Pb-free Halide free	Activ e	1	200	±1.5	2.2	26	-0.3 to 26	0.04	0.04	±0.05	1.5	-40 to 125	135	SC- 88-6 / SC- 70-6 / SOT- 363-6

For more information please contact your local sales support at www.onsemi.com.

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